

## DFB Laser Diode, 15XX nm, 3 GHz, 20 mW, Single Mode DEVICE

OVERVIEW	The Optilab DFB-15XX-DM-3 Directly-Modulated (DM) DFB laser is a high-speed 15XX nm wavelength laser source for 3 GHz analog or 4 Gb/s digital transmission optical link. Built with Distributed Feed-Back Grating (DFB) as cavity reflector, it provides pure, single longitudinal mode, hopping free and extremely stable wavelength source. This laser diode is fabricated with Multiple Quantum Well (MQW) for excellent reliability and stability. It can be used for CW operation for fiber sensor or coherence interferometer. Or with direct current modulation DFB-15XX-DM-3 can be used for DC to 3 GHz analog or up to 4 Gb/s digital modulation. The wavelength choice is from 1529 to 1561 nm. This MQW DFB laser features Up to 20 mW of output optical power, good Side Mode Suppression Ratio (SMSR) and a built-in thermoelectric cooler, thermistor, and rear-facet monitor photodiode for external optical power control. Contact Optilab for more information.
FEATURES	<ul> <li>MQW laser structure with ECL Design</li> <li>Available wavelength: 1529-1561 nm</li> <li>Analog modulation up to 3 GHz</li> <li>Built-in TEC, Thermistor &amp; Monitor PD</li> <li>Up to 20 mW output power typical</li> <li>Side Mode Suppression Ratio 40 dB Min.</li> </ul>

## USE IN

- Stabilized Single Frequency Source
  - Analog RF over fiber
  - DWDM optical network

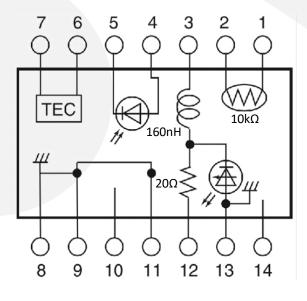
- CW 1550 nm laser source Directly modulated optical link
- 4 Gb/s digital communication

1 Thermistor

FUNCTIONAL DIAGRAM

- 2 Thermistor
- 3 Laser DC Bias (-)
- 4 Monitor Anode
- 5 Monitor Cathode
- 6 TEC (+)
- 7 TEC (-)

- 8 Case Ground
- 9 Case Ground
- 10 Not Connected
- 11 Laser Ground
- 12 Laser Modulation (-)
- 13 Case Ground
- 14 Not Connected







## DFB-15XX-DM-3

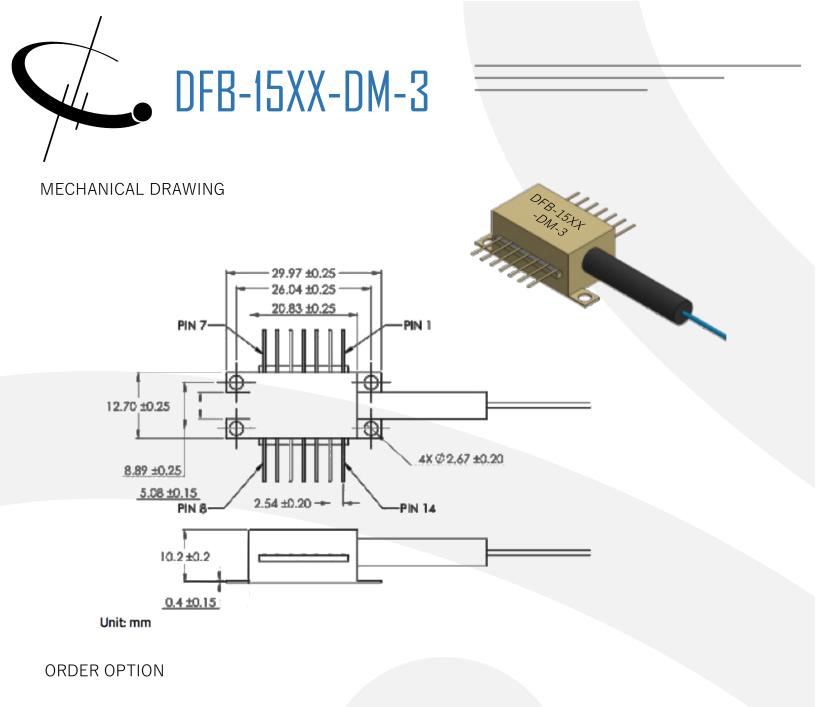
SPECIFICATIONS
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GENERAL	&
MECHANIC	۹L

Center Wavelength Range	1529-1561 nm typ.
Optical Output Power	20 mW
Threshold Current	20 mA max. 🖻 CW
Operating Current	350 mA typ. 🖻 CW
Forward Voltage	1.6 V typ.
Series Resistance	20 Ω typ.
Slope Efficiency	D.1 mW/mA typ.
Threshold Power	0.15 mW
Monitor Current	0.3 mA 🗉 1.0 mW
Side Mode Suppression Ratio	40 dB Min.
Laser Linewidth	2 MHz typ.
Rise/Fall Time (10%-90%)	150 ps typ.
3 dB S21 Bandwidth	2.5 GHz
RF Return Loss	-10 dB from DC to 2.5 GHz
Optical Isolation	35 dB typ.
Relative Intensity Noise	-145 dB/Hz max
Optical Connectors	FC/APC
Optical Fiber Type	SMF-28 (standard)

ABSOLUTE	Wavelength Tuning Coefficient	0.1 nm/°C
MAXIMUM RATING	Operating Temperature	-30 °C to +60 °C
	Storage Temperature	-40 °C to +75 °C
All wavelength/power	Reverse Voltage	2 V
measurement based	LD Current	190 mA
on 25°C	PD Reverse Voltage	10 V
	PD Forward Current	10 mA
	TEC Voltage	2.5 V
	TEC Current	1.4 A
	Lead Soldering Time	10 s 🖻 < 260 °C
EC AND THERMISTOR	TEC Current	1.0 A max.
HARACTERISTICS	TEC Voltage	2.4 V max.
	Cooler Power	2.4W max.
	TEC Resistance	2.0 Ω min., 2.4 Ω typ., 3.2 Ω max.
	Thermistor Resistance	20 Ω typ.
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DFB-15XX-DM-YY				
XX: Wavelength in nanometer	1530 to 1560 nm			
YY: Optical power in mW	20 mW			

